

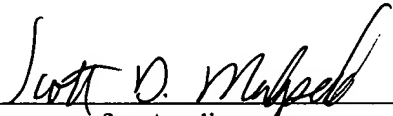
C2 sub 62
9. (Twice Amended) The semiconductor device according to Claim 7,
wherein the deviation of surface from the strict (111) plane is within an angle equal to
24/60ths of a degree ($0^{\circ}24'$).

REMARKS

Claims 7-9 are pending. Claims 7 and 9 have been amended to change
"principal plane" to --surface--. Applicants maintain that the claims are allowable for
reasons similar to those articulated in previous responses. Favorable reconsideration is
again requested.

Applicants' undersigned attorney may be reached in our New York office by
telephone at (212) 218-2100. All correspondence should continue to be directed to our
below listed address.

Respectfully submitted,


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VERSION WITH MARKINGS TO SHOW CHANGES MADE TO CLAIMS

7. (Amended) A semiconductor device comprising a substrate and formed thereon an active layer having the [principal plane] surface of (111)-plane; the active layer being used in photoelectric conversion.

9. (Twice Amended) The semiconductor device according to Claim 7, wherein the deviation of [principal plane] surface from the strict (111) plane is within an angle equal to 24/60ths of a degree ($0^{\circ}24'$).

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